

# STPS640C-Y

Datasheet - production data

### Automotive power Schottky rectifier

#### A1 A2 K K K K K A2 K A2 K A2 A1 A2 A2 A2 A1 DPAK STPS640CBY-TR

### Features

- Low forward voltage drop
- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low thermal resistance
- AEC-Q101 qualified.

### Description

This dual Schottky rectifier is designed for switch mode power supplies and other power converters.

This device is intended for use in low and medium voltage operation, and in particular high frequency circuits where low switching losses are required (free wheeling and polarity protection) in automotive applications.

Symbol	Value
I <sub>F(AV)</sub>	2 x 3 A
V <sub>RRM</sub>	40 V
Тj	150 °C
V <sub>F (Typ)</sub>	0.50 V

#### Table 1. Device summary

DocID025068 Rev 2

This is information on a product in full production.

## 1 Characteristics

Symbol	Parameter			Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage		40	V
I <sub>F(RMS)</sub>	Forward rms current		6	А
	Average forward current, $\delta = 0.5$ , T <sub>c</sub> = 135 °C	per diode	3	А
I <sub>F(AV)</sub>	Average forward current, $0 = 0.5$ , $T_c = 155$ C	per device	6	A
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}, T_c = 25 \text{ °C}$		°C 75	А
I <sub>RRM</sub>	Peak repetitive reverse current $t_p = 2 \ \mu s, F = 1 \text{kHz}$		1	А
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 1 \ \mu s, T_c = 25 \ ^{\circ}C$		1300	W
T <sub>stg</sub>	Storage temperature range			°C
Тј	Operating junction temperature			°C

#### Table 2. Absolute ratings (limiting values, per diode)

#### Table 3. Thermal parameters

Symbol	Parameter	Value	Unit	
P	Junction to case	diode	5.5	
R <sub>th(j-c)</sub> Junctio		device	3	°C/W
R <sub>th(c)</sub>	coupling		0.5	

When the diodes 1 and 2 are used simultaneously :  $\Delta$ Tj(diode 1) = P(diode1) x R<sub>th(j-c)</sub>(Per diode) + P(diode 2) x R<sub>th(c)</sub>

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	Deverse leekege ourrent	T <sub>j</sub> = 25 °C	V V	-	-	100	μA
	T <sub>j</sub> = 125 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	2	10	mA	
V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	1 2 4	-	-	0.63		
	Forward voltage drep	T <sub>j</sub> = 125 °C	I <sub>F</sub> = 3 A	-	0.50	0.57	V
	Folward voltage diop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 6 A	-	-	0.84	
		T <sub>j</sub> = 125 °C		-	0.67	0.72	

1. Pulse test:  $t_p = 5 \text{ ms}, \delta < 2\%$ 

2. Pulse test:  $t_p$  = 380 µs,  $\delta$  < 2%

To evaluate the conduction losses use the following equation: P = 0.42 x  $I_{F(AV)}$  + 0.050 x  ${I_F}^2_{(RMS)}$ 



#### Figure 1. Average forward power dissipation versus average forward current (per diode)

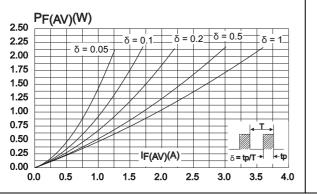


Figure 2. Average forward current versus ambient temperature ( $\delta = 0.5$ , per diode)

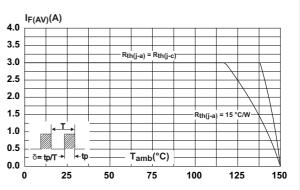


Figure 3. Normalized avalanche power derating Figure 4. Normalized avalanche power derating versus pulse duration

versus junction temperature

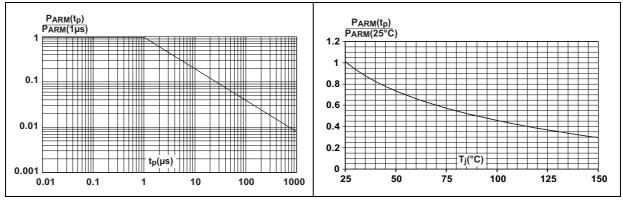
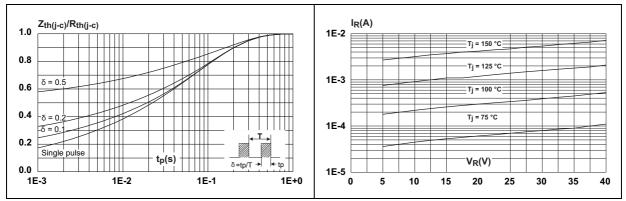
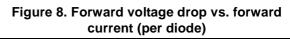


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

Figure 6. Reverse leakage current vs. reverse voltage applied (typical values, per diode)



# Figure 7. Junction capacitance vs. reverse voltage applied (typical values, per diode)



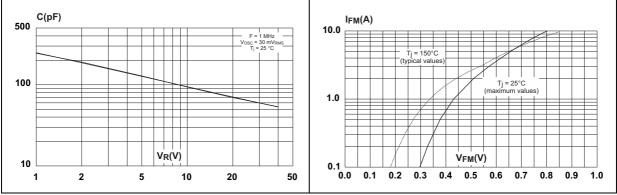
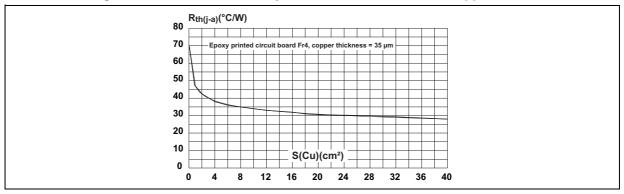


Figure 9. Thermal resistance junction to ambient versus copper surface under tab

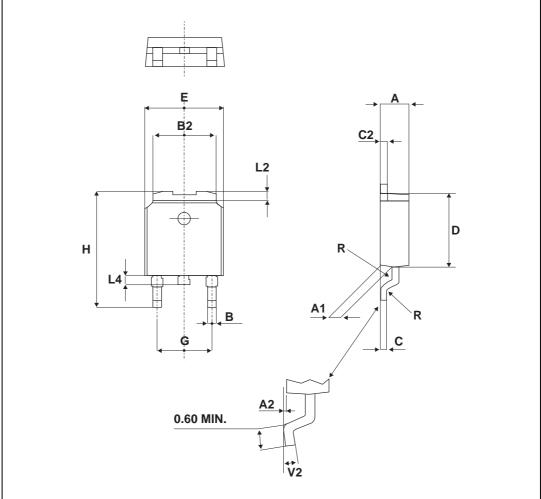


### 2 Package information

- Epoxy meets UL94,V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK<sup>®</sup> is an ST trademark.



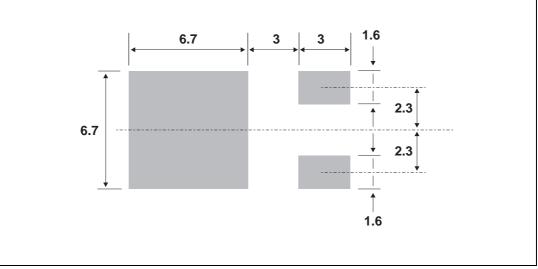




	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	2.20		2.40	0.086		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.212
С	0.45		0.60	0.017		0.023
C2	0.48		0.60	0.018		0.023
D	6.00		6.20	0.236		0.244
Е	6.40		6.60	0.251		0.259
G	4.40		4.60	0.173		0.181
Н	9.35		10.10	0.368		0.397
L2		0.80 typ.			0.031 typ.	
L4	0.60		1.00	0.023		0.039
V2	0°		8°	0°		8°

Table 5. DPAK dimension values

## Figure 11. Footprint dimensions in mm (inches)





## 3 Ordering information

Order code	Marking	Package	ackage Weight Bas		Delivery mode	
STPS640CBY-TR	STPS640CY	DPAK	0.3 g	2500	Tape and reel	

## 4 Revision history

#### Table 7. Revision history

Date	Revision	Changes
6-Nov-2013	1	First issue
04-Dec-2013	2	Properties changed from preliminary data to production data.



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